

Dual N-Channel 20 V MOSFET

PRODUCT SUMMARY

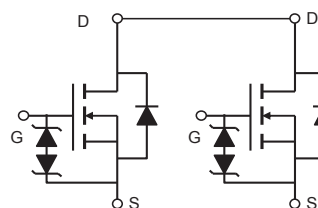
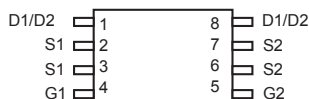
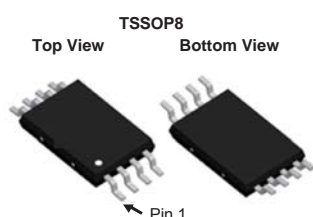
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)
20	0.0095 at V _{GS} = 4.5 V	11 ^a	14.5
	0.0113 at V _{GS} = 2.5 V	9	

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R_g Tested
- 100 % UIS Tested
- Compliant to RoHS Directive 2002/95/EC
- ESD Protected 2KV HBM



RoHS
COMPLIANT
HALOGEN
FREE



ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	± 12	
Continuous Drain Current (T _J = 150 °C)	T _C = 25 °C	I _D	11	A
	T _C = 70 °C		9.9	
	T _A = 25 °C		10.5 ^{b, c}	
	T _A = 70 °C		8.2 ^{b, c}	
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	30	
Source-Drain Current Diode Current	T _C = 25 °C	I _S	2.7	
	T _A = 25 °C		1.6 ^{b, c}	
Pulsed Source-Drain Current		I _{SM}	30	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	10	
Single Pulse Avalanche Energy		E _{AS}	10	
Maximum Power Dissipation	T _C = 25 °C	P _D	3.25	W
	T _C = 70 °C		2.10	
	T _A = 25 °C		2.0 ^{b, c}	
	T _A = 70 °C		1.25 ^{b, c}	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typ.	Max.	Unit
Maximum Junction-to-Ambient ^{b, d}	R _{thJA}	45	62.5	°C/W
Maximum Junction-to-Foot (Drain)	R _{thJF}	29	38	

Notes:

a. Based on T_C = 25 °C.

b. Surface mounted on 1" x 1" FR4 board.

c. t = 10 s.

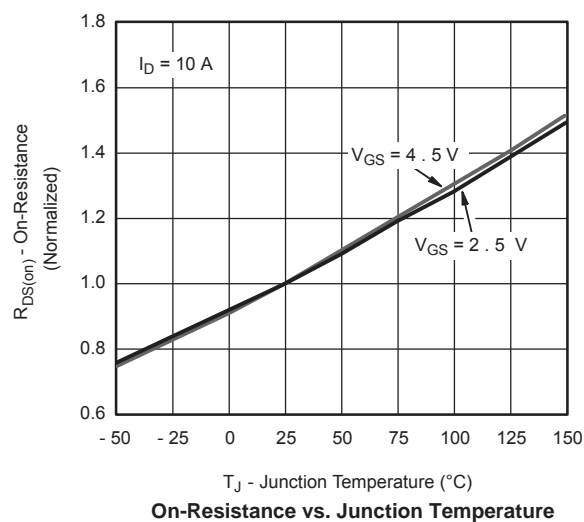
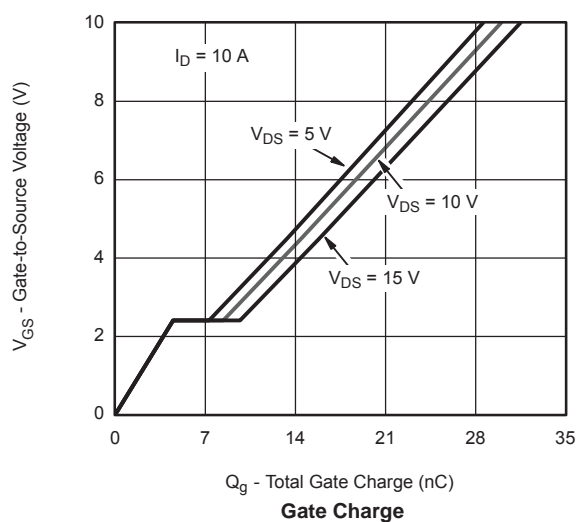
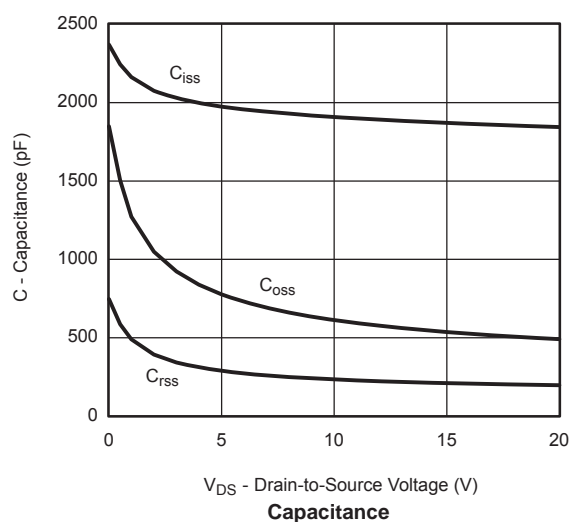
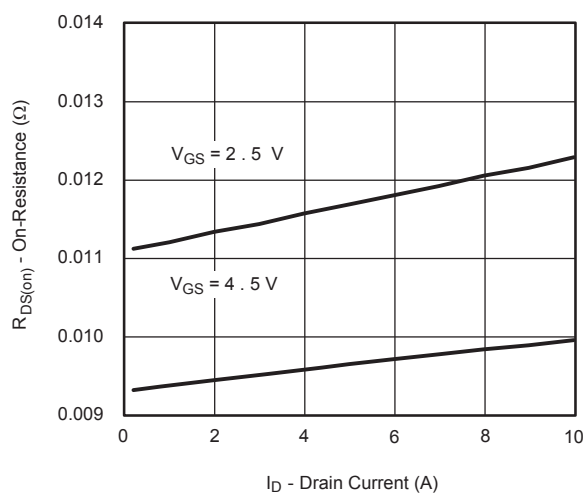
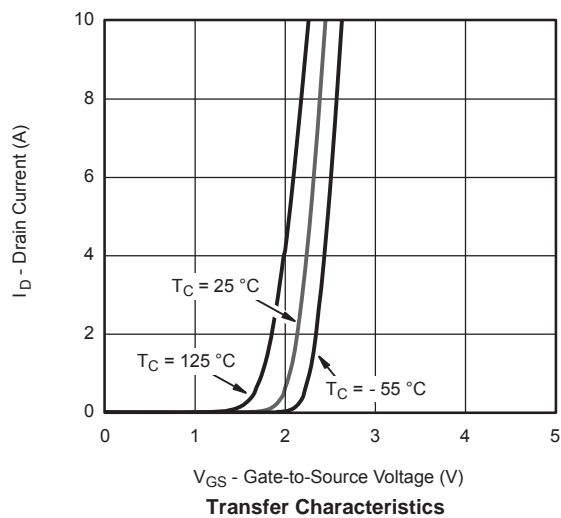
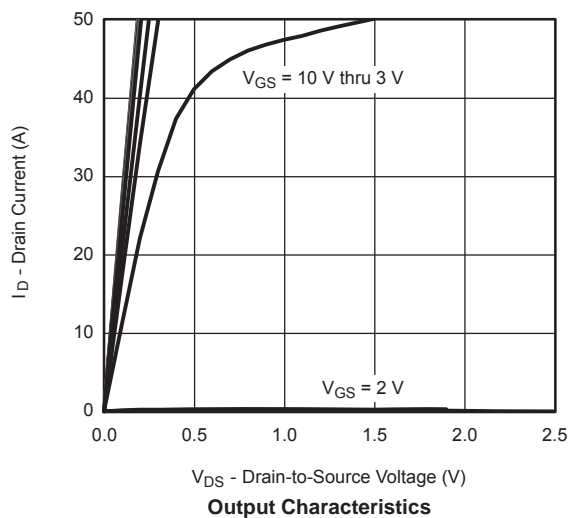
d. Maximum under steady state conditions is 120 °C/W.

SPECIFICATIONS $T_J = 25\text{ }^{\circ}\text{C}$, unless otherwise noted

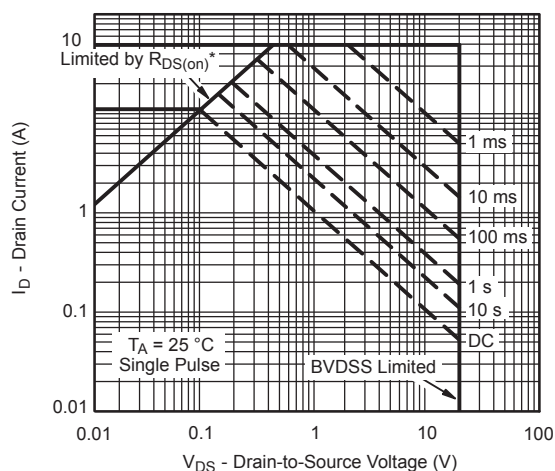
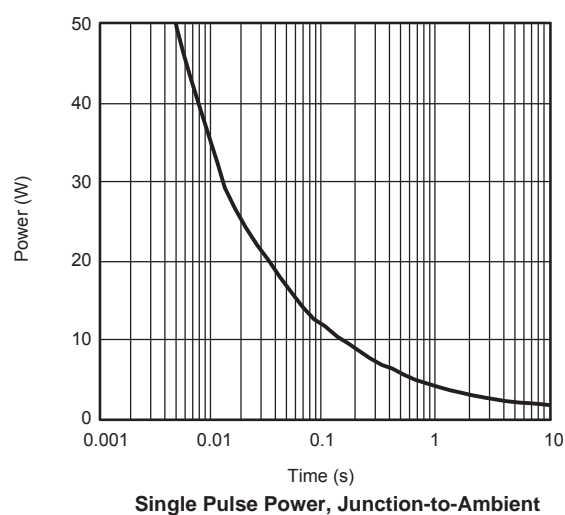
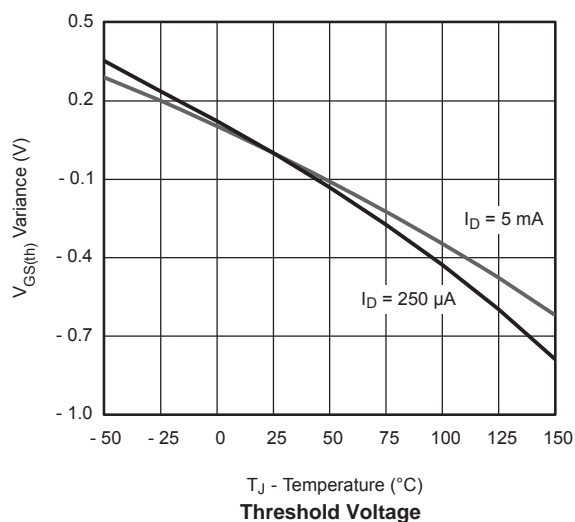
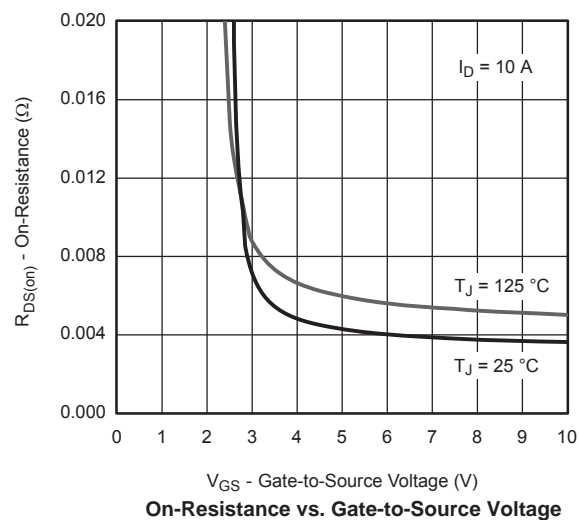
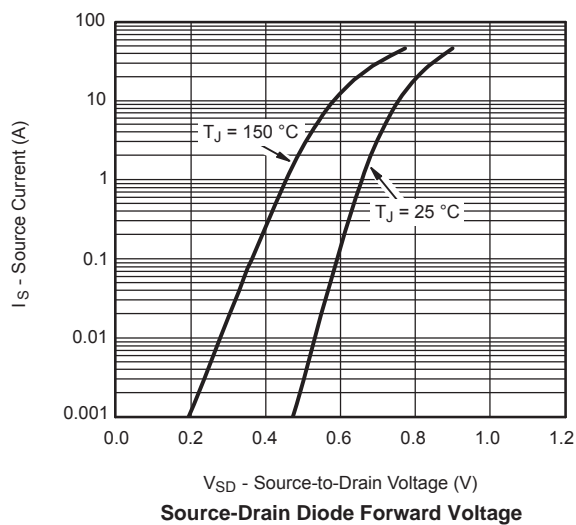
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	20			V
V _{DS} Temperature Coefficient	ΔV _{DS} /T _J	I _D = 250 μA		20		mV/°C
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)} /T _J	I _D = 250 μA		- 5.8		
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	0.6		1.2	V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V			10	uA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 16 V, V _{GS} = 0 V			1	μA
		V _{DS} = 16 V, V _{GS} = 0 V, T _J = 55 °C			10	
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	11			A
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 10 A		0.0095	0.0119	Ω
		V _{GS} = 2.5 V, I _D = 8 A		0.0113	0.0148	
Forward Transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 10 A		50		S
Dynamic ^a						
Input Capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, I _D = 1 MHz		2110		pF
Output Capacitance	C _{oss}			926		
Reverse Transfer Capacitance	C _{rss}			235		
Total Gate Charge	Q _g	V _{DS} = 10 V, V _{GS} = 10 V, I _D = 10 A		30	45	nC
Gate-Source Charge	Q _{gs}	V _{DS} = 10 V, V _{GS} = 4.5 V, I _D = 10 A		14.5	22	
Gate-Drain Charge	Q _{gd}			4.5		
Gate Resistance	R _g	f = 1 MHz	0.4	1.4	2.8	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = 10 V, R _L = 1 Ω I _D ≅ 10 A, V _{GEN} = 10 V, R _g = 1 Ω		8	16	ns
Rise Time	t _r			15	30	
Turn-Off Delay Time	t _{d(off)}			24	45	
Fall Time	t _f			9	18	
Turn-On Delay Time	t _{d(on)}	V _{DD} = 10 V, R _L = 1 Ω I _D ≅ 10 A, V _{GEN} = 4.5 V, R _g = 1 Ω		18	35	
Rise Time	t _r			24	45	
Turn-Off Delay Time	t _{d(off)}			26	50	
Fall Time	t _f			13	26	
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			2.7	A
Pulse Diode Forward Current ^a	I _{SM}				30	
Body Diode Voltage	V _{SD}	I _S = 3 A		0.70	1.2	V
Body Diode Reverse Recovery Time	t _{rr}	N-Channel I _F = 10 A, dI/dt = 100 A/μs, T _J = 25 °C		20	40	ns
Body Diode Reverse Recovery Charge	Q _{rr}			10	20	nC
Reverse Recovery Fall Time	t _a			11		nS
Reverse Recovery Rise Time	t _b			9		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



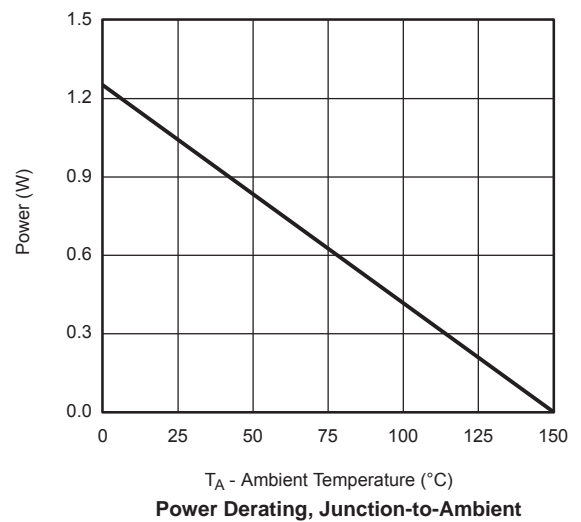
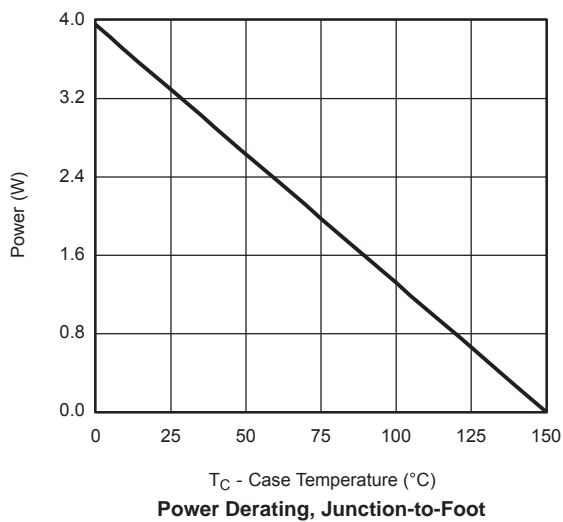
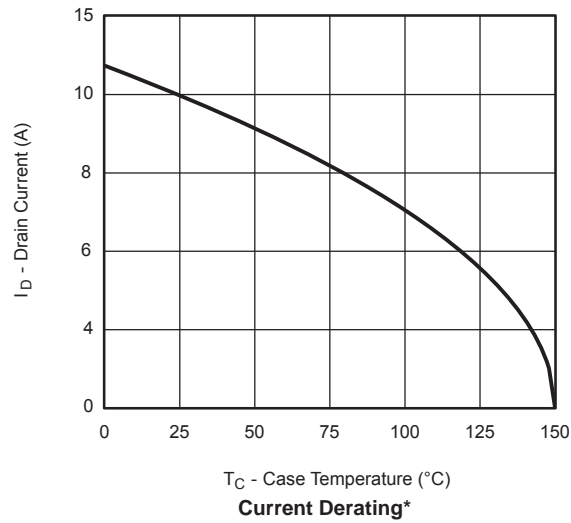
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

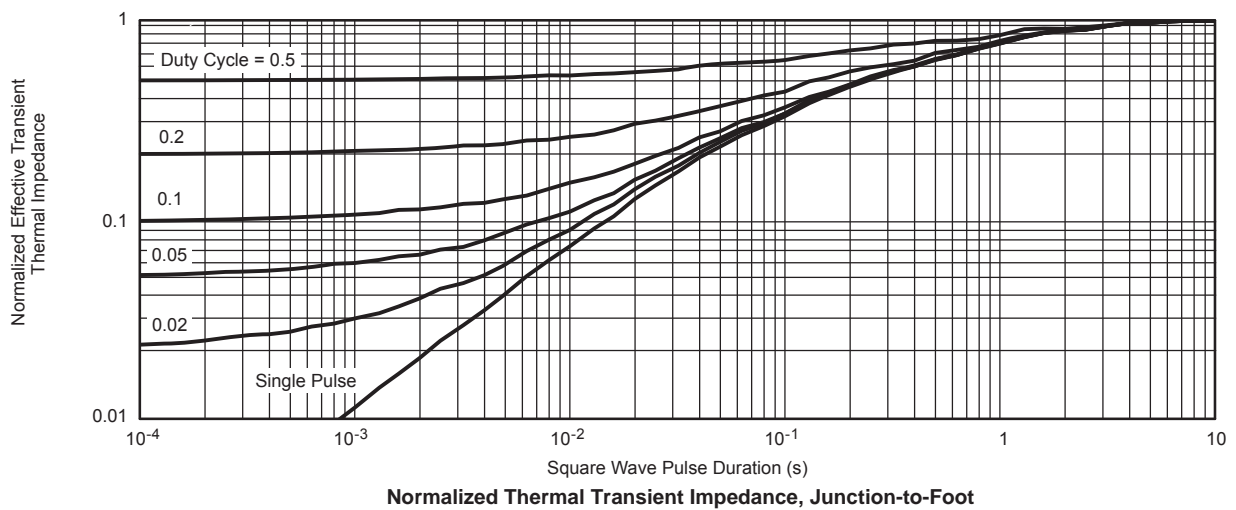
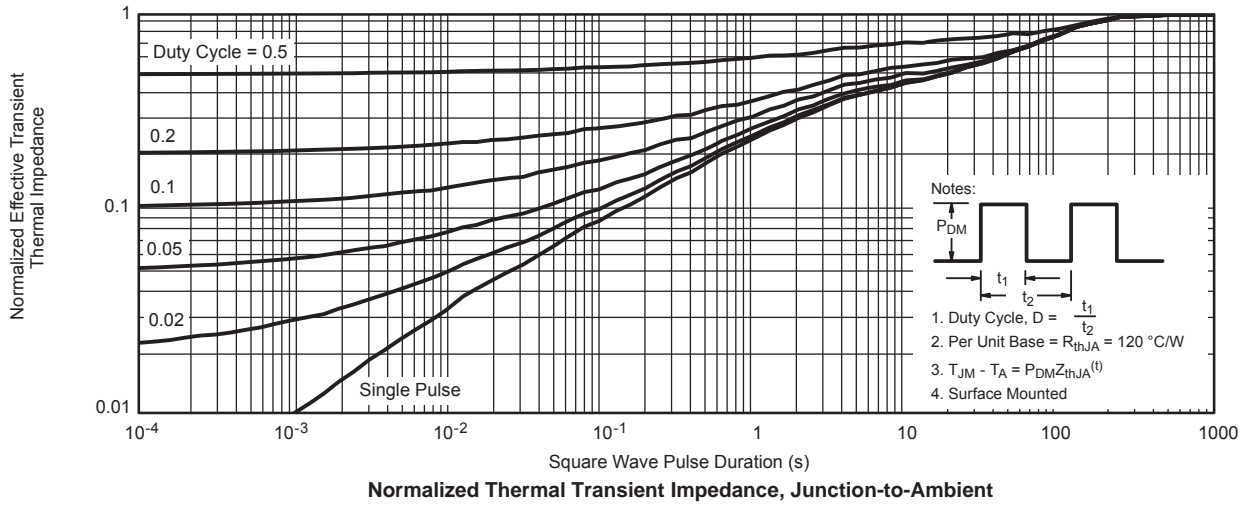
Safe Operating Area, Junction-to-Ambient

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



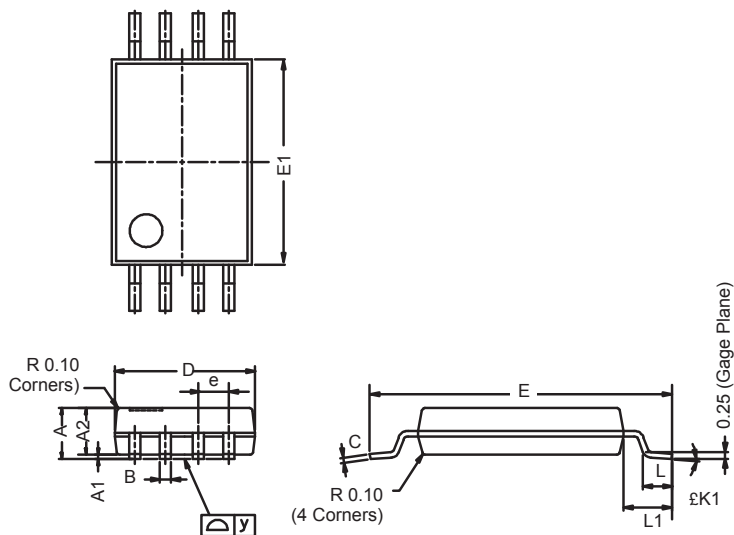
* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



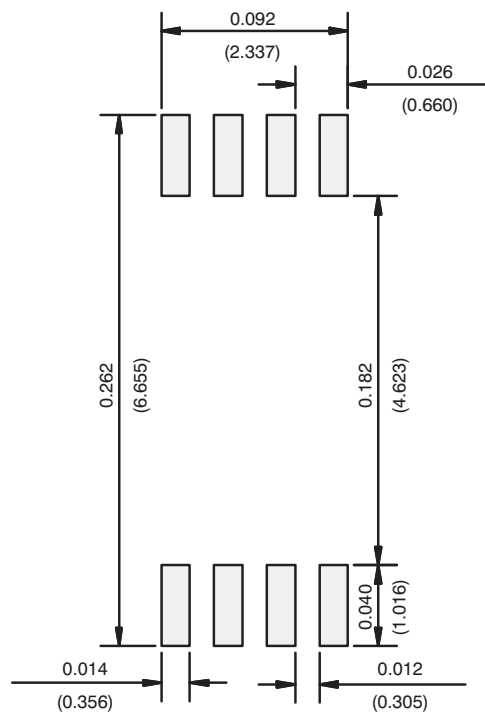
TSSOP: 8-LEAD

JEDEC Part Number: MO-153



Dim	MILLIMETERS		
	Min	Nom	Max
A	—	—	1.20
A₁	0.05	0.10	0.15
A₂	0.80	1.00	1.05
B	0.19	0.28	0.30
C	—	0.127	—
D	2.90	3.00	3.10
E	6.20	6.40	6.60
E₁	4.30	4.40	4.50
e	—	0.65	—
L	0.45	0.60	0.75
L₁	0.90	1.00	1.10
Y	—	—	0.10
°K1	0°	3°	6°
ECN: S-03946—Rev. G, 09-Jul-01 DWG: 5844			

RECOMMENDED MINIMUM PADS FOR TSSOP-8



Recommended Minimum Pads
Dimensions in Inches/(mm)

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